

FX20KMJ-2

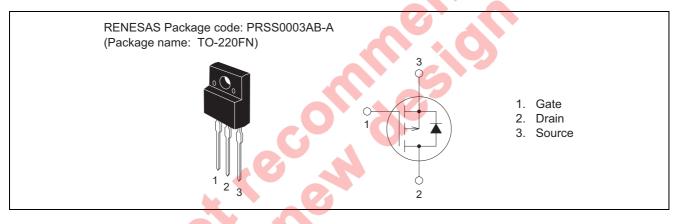
High-Speed Switching Use Pch Power MOS FET

> REJ03G1443-0200 (Previous: MEJ02G0282-0101) Rev.2.00 Aug 07, 2006

Features

- Drive voltage : 4 V
- V_{DSS} : 100 V
- $r_{\text{DS(ON)}(\text{max})}$: 0.26 Ω
- $I_D := -20 A$
- Integrated Fast Recovery Diode (TYP.): 100 ns
- Viso : 2000 V

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

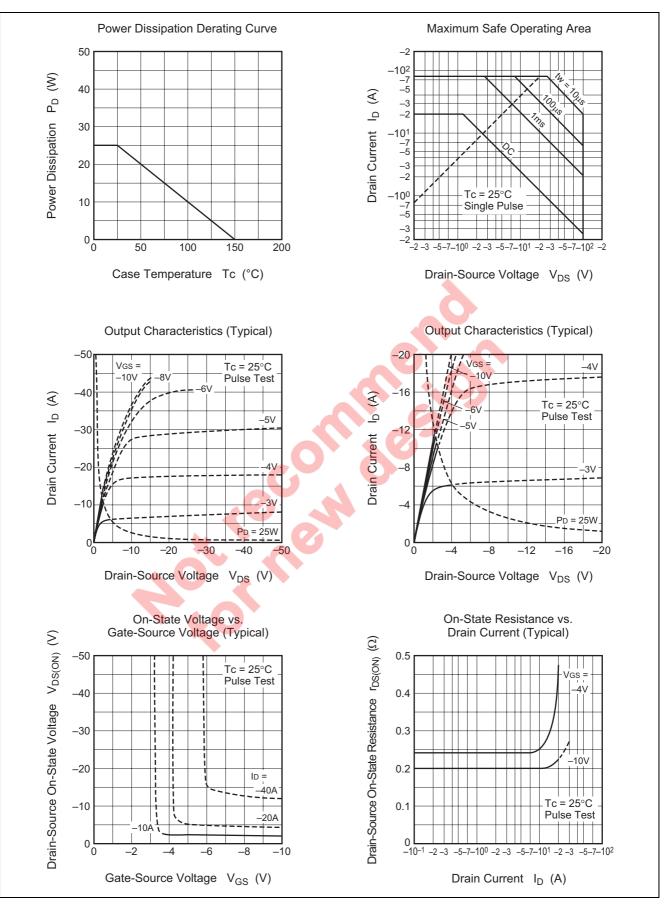
				$(\mathrm{Tc} = 25^{\circ}\mathrm{C})$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	-100	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	ID	-20	A	
Drain current (Pulsed)	I _{DM}	-80	A	
Avalanche drain current (Pulsed)	I _{DA}	-20	A	L = 50 μH
Source current	Is	-20	A	
Source current (Pulsed)	I _{SM}	-80	A	
Maximum power dissipation	PD	25	W	
Channel temperature	Tch	- 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Isolation voltage	Viso	2000	V	AC for 1 minute,
-				Terminal to case
Mass		2.0	g	Typical value



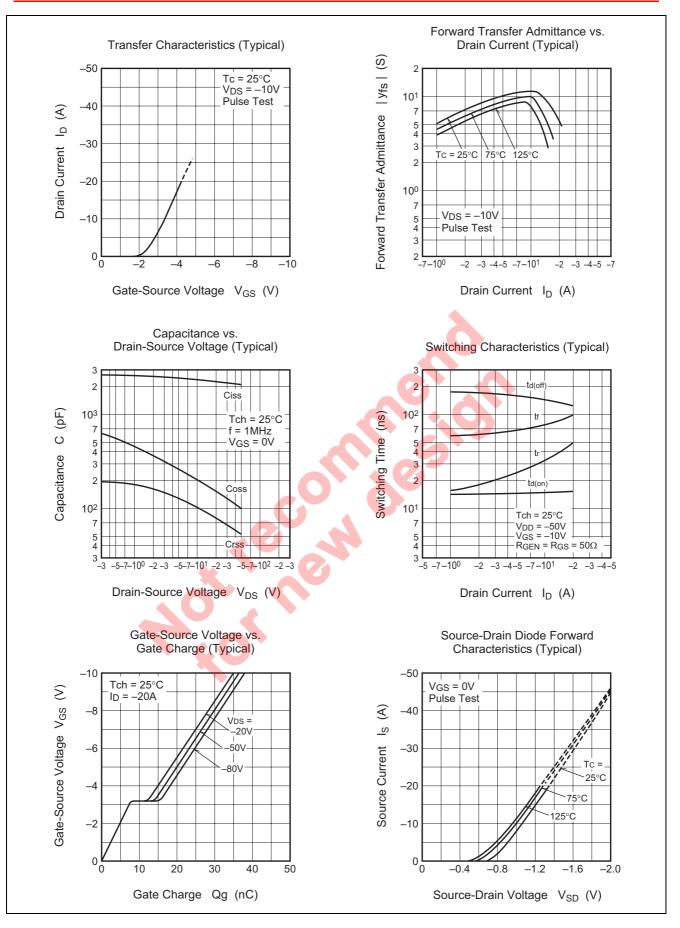
Electrical Characteristics

						$(Tch = 25^{\circ}C)$
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain-source breakdown voltage	V _{(BR)DSS}	-100	—	_	V	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate-source leakage current	I _{GSS}	—	—	±0.1	μΑ	V_{GS} = ±20 V, V_{DS} = 0 V
Drain-source leakage current	I _{DSS}	—	_	-0.1	mA	$V_{DS} = -100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$
Gate-source threshold voltage	V _{GS(th)}	-1.3	-1.8	-2.3	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	0.20	0.26	Ω	$I_D = -10 \text{ A}, \text{ V}_{GS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	0.25	0.32	Ω	$I_D = -10 \text{ A}, \text{ V}_{GS} = -4 \text{ V}$
Drain-source on-state voltage	V _{DS(ON)}	—	-2.0	-2.6	V	$I_D = -10 \text{ A}, \text{ V}_{GS} = -10 \text{ V}$
Forward transfer admittance	y _{fs}	_	10.3	_	S	$I_D = -10 \text{ A}, \text{ V}_{DS} = -10 \text{ V}$
Input capacitance	Ciss	—	2360	_	pF	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$
Output capacitance	Coss	—	198	_	pF	f = 1MHz
Reverse transfer capacitance	Crss	—	99	_	pF	
Turn-on delay time	t _{d(on)}	—	13	_	ns	$V_{DD} = -50 \text{ V}, I_D = -10 \text{ A},$
Rise time	tr	—	30	_	ns	$V_{GS} = -10 V$,
Turn-off delay time	t _{d(off)}	—	139		ns	$R_{GEN} = R_{GS} = 50 \ \Omega$
Fall time	t _f	—	74	—	ns	
Source-drain voltage	V _{SD}	—	-1.0	-1.5	V	$I_{S} = -10 \text{ A}, V_{GS} = 0 \text{ V}$
Thermal resistance	R _{th(ch-c)}	—	—	5.00	°C/W	Channel to case
Reverse recovery time	trr	—	100		ns	$I_{\rm S} = -20$ A, $d_{\rm is}/d_{\rm t} = 100$ A/µs

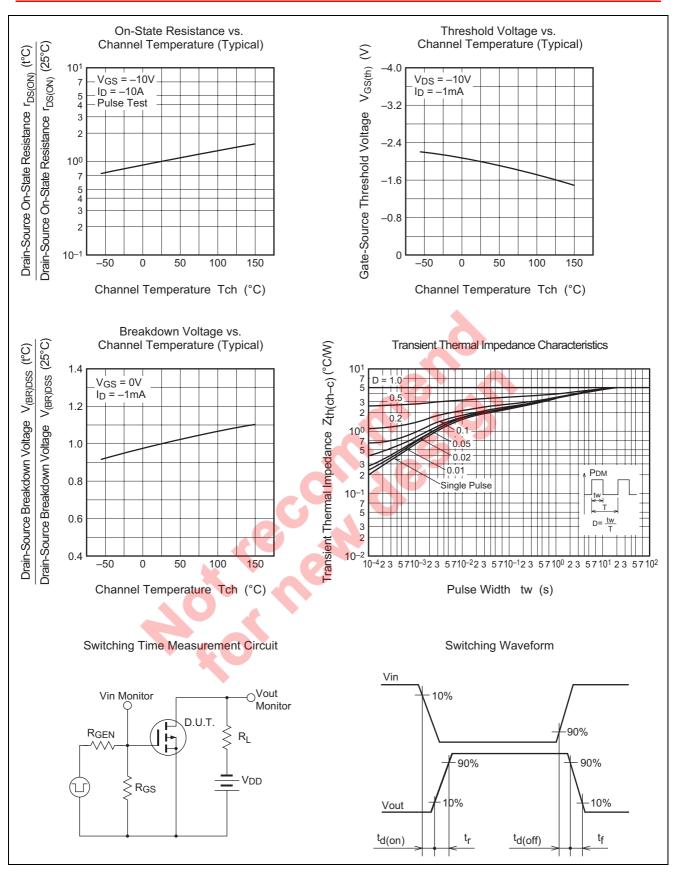
Performance Curves





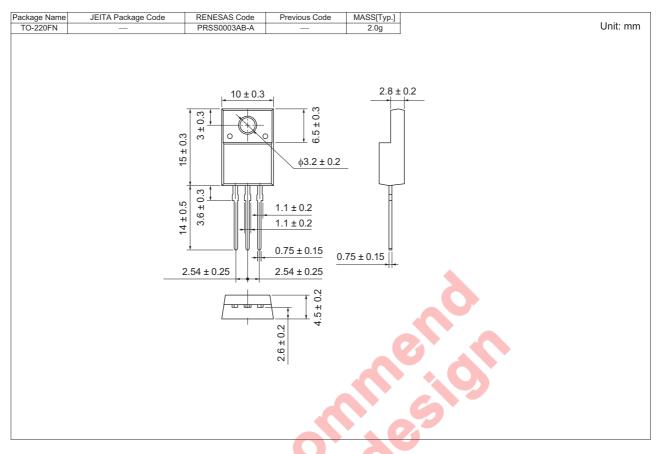








Package Dimensions



Order Code

Lead form	Standard packing	Qu	antity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)		50	Type name	FX20KMJ-2
Lead form	Plastic Magazine (Tube)		50	Type name – Lead forming code	FX20KMJ-2-A8

Note: Please confirm the specification about the shipping in detail.

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